

May 7, 2009

TriQuint, ZTE Sign \$50m Agreement at US-China Business Forum

Forum Yields \$5.7B across 28 contracts

HILLSBORO, OR (USA) – May 7, 2009 – TriQuint Semiconductor (Nasdaq: **TQNT**), a leading RF product manufacturer and foundry services provider, announced it has signed a framework agreement with ZTE Corporation, a leading manufacturer in China for wireless communication system equipment. The document states ZTE will procure TriQuint components, including but not limited to CDMA, GSM, and WCDMA ASICs, in the value of no less than \$50 million U.S. dollars in the 2009 calendar year.

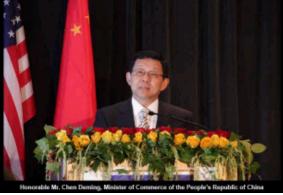
The agreement was formalized at the US-China Business Signing Ceremony: *Partnering for Sustainable Economic Growth*, April 28, 2009, in Chicago, IL. The event, aggregating \$5.7 billion dollars of US-China business through 28 contracts, was organized by the China Chamber of Commerce for Import & Export of Machinery and Electronic Products. Welcome remarks were given by the Honorable Mr. Chen Deming, Minister of Commerce of the People's Republic of China. The signings were witnessed by Vice Minister Ma Xiuhong and Consul General Huang Ping.

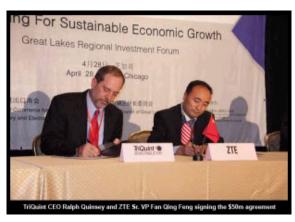
Mr. Chen said that at a time of historic uncertainty, it is more important than ever to expedite trade and investment activities, in order to enhance our already productive partnerships and improve economic prosperity.

"We were delighted to be invited by ZTE to this event supporting international relations, and look forward to working with ZTE to further wireless communications," said Ralph Quinsey, President and CEO of TriQuint Semiconductor. "Not only does this agreement strengthen the relationship of the two companies, but our innovations will bring high quality voice, data, and video communications to people everywhere."

For more information about TriQuint products and foundry services, visit <u>www.triquint.com</u>. Register for product updates and our newsletter at: www.triquint.com/rf.













FORWARD LOOKING STATEMENTS

This TriQuint Semiconductor, Inc. (Nasdaq: TQNT) press release contains forward-looking statements made pursuant to the Safe Harbor provisions of the Private Securities Litigation Reform Act of 1995. Readers are cautioned that forward-looking statements involve risks and uncertainties. The cautionary statements made in this press release should be read as being applicable to all related statements wherever they appear. Statements containing such words as 'will procure', '50 million dollars', or similar terms are considered to contain uncertainty and are forward-looking statements. A number of factors affect TriQuint's operating results and could cause its actual future results to differ materially from any results indicated in this press release or in any other forward-looking statements made by, or on behalf of, TriQuint including, but not limited to: those associated with the unpredictability and volatility of customer acceptance of and demand for our products and technologies, the ability of our production facilities and those of our vendors to meet demand, the ability of our production facilities and those of our vendors to produce products with yields sufficient to maintain profitability, as well as the other "Risk Factors" set forth in TriQuint's most recent 10-Q report filed with the Securities and Exchange Commission. This and other reports can be found on the SEC web site, www.sec.gov. A reader of this release should understand that these and other risks could cause actual results to differ materially from expectations expressed / implied in forward-looking statements.

FACTS ABOUT TRIQUINT

Founded in 1985, we "Connect the Digital World to the Global Network" by supplying high-performance RF modules, components and foundry services to the world's leading communications companies. Specifically, TriQuint supplies products to four out of the top five mobile phone manufacturers, and is a leading gallium arsenide (GaAs) supplier to major defense and space contractors. TriQuint creates standard and custom products using advanced processes that include gallium arsenide, surface acoustic wave (SAW) and bulk acoustic wave (BAW) technologies to serve diverse markets including wireless handsets, laptops, GPS/PND, base stations, broadband communications and military. TriQuint is also the lead researcher in a multi-year DARPA program to develop advanced gallium nitride (GaN) amplifiers. TriQuint, as named by Strategy Analytics 1, is the number-three worldwide leader in GaAs devices and the world's largest commercial GaAs foundry. TriQuint has ISO9001 certified manufacturing facilities in Oregon, Texas, and Florida and a production plant in Costa Rica; design centers are located in North America and Germany. Visit TriQuint at www.triquint.com/rf to receive new product information and to register for our newsletters.

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¹ Announced February 2009 and August 2008, respectively.